

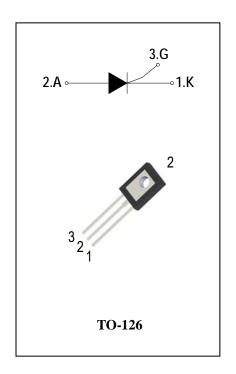
# **SCRs**

# **General Description**

Available either in sensitive or standard gate triggering levels, the 4A SCR series is suitable to fit all modes of control found inapplications such as overvoltage crowbar protection, motor control circuits in power tools and kitchen aids, in-rush current limiting circuits, capacitive discharge ignition, voltage regulation circuits...

#### **Features**

- ◆ Repetitive Peak Off-State Voltage: 600V and 800V
- ◆ R.M.S On-State Current (IT(RMS)= 4A)
- ♦ These are Pb-Free Devices



# **Absolute Maximum Ratings**

Symbol	Items	Conditions		Ratings	Unit
$V_{DRM}$	Repetitive Peak Off-State Voltage	T:-25°C	ADT4A60B	600	V
$V_{RRM}$	Repetitive peak reverse voltage	Tj=25°C	ADT4A80B	800	V
I <sub>T(AV)</sub>	Average On-State Current	Half Sine Wave , Tc = 100°C		3.5	Α
I <sub>T(RMS)</sub>	R.M.S On-State Current	Half Sine Wave , Tc = 100°C		4	Α
I <sub>TSM</sub>	Surge On-State Current	1/2 Cycle, Sine Wave Non-Repetitive, tp=10ms(50Hz)Tj =25°C		36	Α
l <sup>2</sup> t	I <sup>2</sup> t for Fusing	Tj =25°C,tp =10ms		4.5	A <sup>2</sup> S
dI/dt	Critical rate of rise of on-state current	Tj =125°C, tr≤ 100ns		50	A/µs
$P_{GM}$	Forward Peak Gate Power Dissipation	Tj =125°C, Pulse Width ≤ 20μs		2	W
$P_{G(AV)}$	Forward Average Gate Power Dissipation	Tj =25°C, tp =10ms		0.2	W
$I_{GM}$	Peak Gate Current	Tj =125°C, Pulse Width ≤ 20μs		1.2	Α
Tj	Operating Junction Temperature			- 40 ~ 125	°C
T <sub>STG</sub>	Storage Temperature			- 40 ~ 150	°C





# **ADT4A60B/80B**

# **Electrical Characteristics** (Tj = 25°C unless otherwise specified)

Symbol	Items	Conditions		ADT4A60B/80B		Unit
				Т	S	
		$V_{DRM} = V_{RRM}, R_{GK} = 1K\Omega$		:	5	uA
I <sub>DRM</sub>	Peak Forward Reverse	Tj = 25°C	Max.			
I <sub>RRM</sub>	Blocking Current	$V_{DRM} = V_{RRM}, R_{GK} = 1K\Omega$ $Tj = 125^{\circ}C$	Wax.	1		mA
$V_{TM}$	Peak On-State Voltage	I <sub>TM</sub> = 10A, t <sub>p</sub> = 380 μs	Max.	1.7		V
$V_{\sf GD}$	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $R_{GK} = 1 \text{K}\Omega$ $Tj = 125 ^{\circ}\text{C}$	Min.	0.2		V
$V_{GT}$	Gate Trigger Voltage	V 40V B 000	Max.	1.3		V
I <sub>GT</sub>	Gate Trigger Current	$V_D = 12V$ , $R_L = 33\Omega$	Max.	0.2	15	mA
I <sub>H</sub>	Holding Current	$I_T = 0.05A$ $R_{GK} = 1K\Omega$	Max.	5	30	mA
ΙL	Latching Current	$I_G$ = 1.2 $I_{GT}$ $R_{GK}$ = 1K $\Omega$	Max.	6	50	mA
dV/dt	Critical Rate of Rise of Off-State Voltage	$V_D = 2/3V_{DRM}$ gate open $R_{GK} = 1K\Omega$ $Tj = 125^{\circ}C$	Min.	5	150	V/µs
R <sub>th(j-c)</sub>	Junction to case		Max.	7.2		°C/W
R <sub>th(j-a)</sub>	Junction to ambient		Max.	60		°C/W

FIG.2: Average on-state current VS Allowable

# **ADV**

FIG.1: Maximum average power dissipation (Single phase half wave)

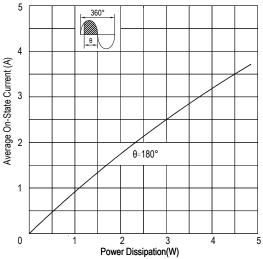


FIG.3: Gate trigger current VS Junction temperature

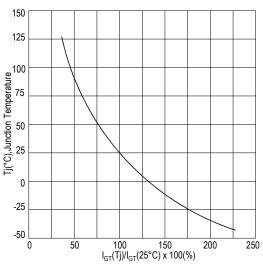


FIG.5: On-state characteristics(Max)

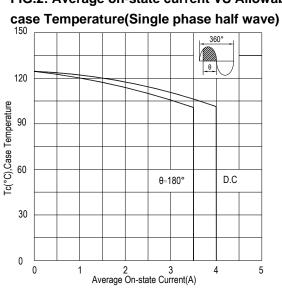
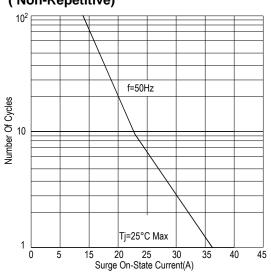


FIG.4: Rated surge on-state current (Non-Repetitive)



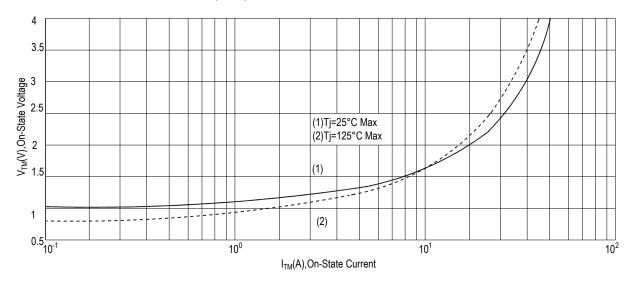






FIG.6:Holding current and Latching current VS Junction temperature

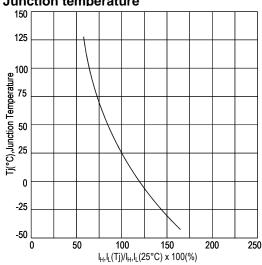


FIG.8: Gate trigger current VS Junction temperature for type T gate triggering

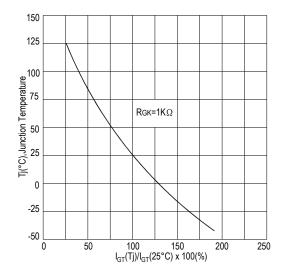


FIG.7: Gate trigger voltage VS Junction

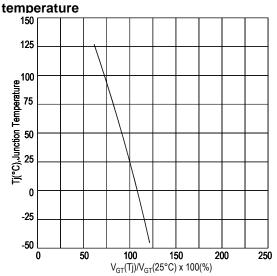
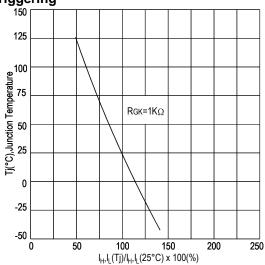


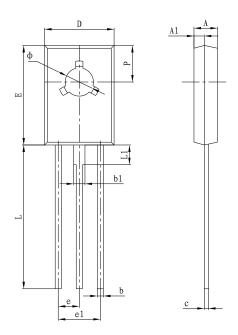
FIG.8:Holding current and Latching current
VS Junction temperature for type T gate
triggering





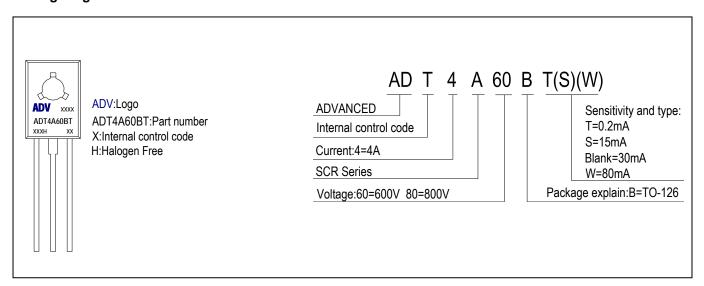
#### **PACKAGE MECHANICAL DATA**

## TO-126 Package Dimension



Sy	Dimens	ions In	Dimensions In		
mb	Millimeters		Inches		
ol	Min	Max	Min	Max	
Α	2.500	2.900	0.098	0.114	
A1	1.100	1.500	0.043	0.059	
b	0.660	0.860	0.026	0.034	
b1	1.170	1.370	0.046	0.054	
С	0.450	0.600	0.018	0.024	
D	7.400	8.000	0.291	0.315	
Е	10.600	11.000	0.417	0.433	
е	2.290 TYP		0.090 TYP		
e1	4.480	4.680	0.176	0.184	
L	15.300	15.700	0.602	0.618	
L1	2.100	2.300	0.083	0.091	
Р	3.900	4.100	0.154	0.161	
Ф	3.000	3.200	0.118	0.126	

### **Making Diagram**



# **Ordering information**

Part number	Package	Marking	Packing	Quantity		
ADT4A60B#	TO-126	ADT4A60B#	Vinyl sack	500pcs		
ADT4A80B#	TO-126	ADT4A80B#	Vinyl sack	500pcs		
Note:# = Gate Trigger Current Sensitivity and type						



# ADT4A60B/80B

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